

KA1L0365R/KA1M0365R/KA1H0365R

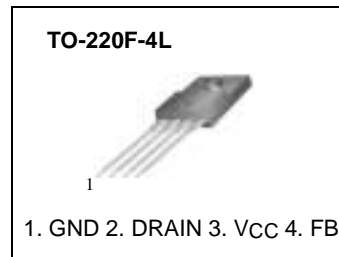
Fairchild Power Switch(FPS)

Features

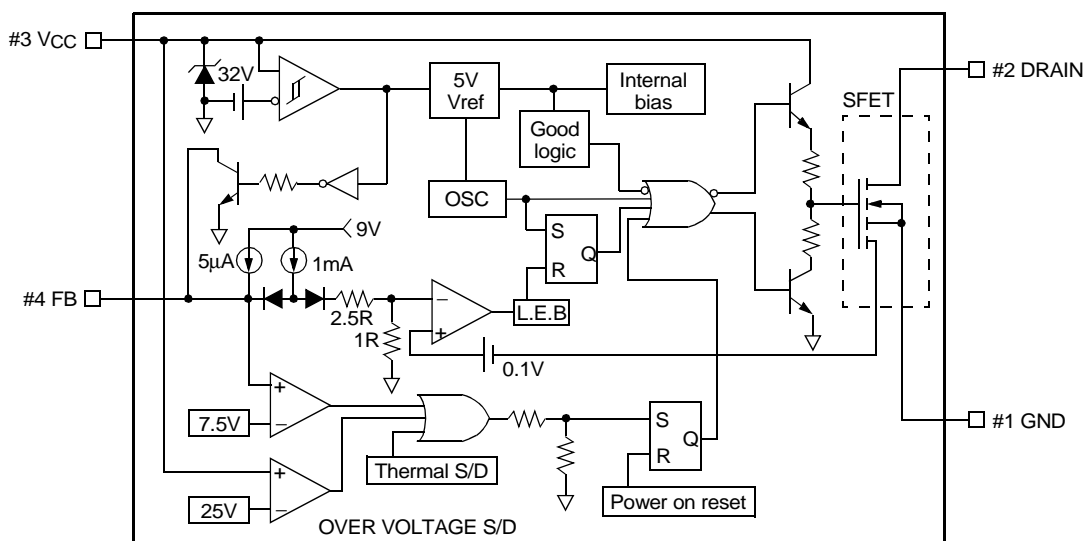
- Precision Fixed Operating Frequency
- KA1L0365R(50kHz), KA1M0365R(67kHz), KA1H0365R(100kHz)
- Pulse by Pulse Over Current Limiting
- Over Load Protection
- Over Voltage Protection (Min. 23V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto Restart

Description

The Fairchild Power Switch(FPS) product family is specially designed for an off line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM controller IC. PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, temperature compensated precision current sources for loop compensation and fault protection circuit. compared to discrete MOSFET and controller or RCC switching converter solution, a Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase & efficiency, productivity, and system reliability. It has a basic platform well suited for cost effective design in either a flyback converter or a forward converter.



Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Maximum Drain Voltage ⁽¹⁾	V _{D,MAX}	650	V
Drain-Gate Voltage (R _{GS} =1MΩ)	V _{DGR}	650	V
Gate-Source (GND) Voltage	V _{GS}	±30	V
Drain Current Pulsed ⁽²⁾	I _{DM}	12	ADC
Single Pulsed Avalanche Energy ⁽³⁾	E _{AS}	358	mJ
Continuous Drain Current (T _C =25°C)	I _D	3.0	ADC
Continuous Drain Current (T _C =100°C)	I _D	2.4	ADC
Maximum Supply Voltage	V _{CC,MAX}	30	V
Input Voltage Range	V _{FB}	-0.3 to V _{SD}	V
Total Power Dissipation	P _D	75	W
	Darting	0.6	W/°C
Operating Ambient Temperature	T _A	-25 to +85	°C
Storage Temperature	T _{STG}	-55 to +150	°C

Notes:

1. T_j = 25°C to 150°C
2. Repetitive rating: Pulse width limited by maximum junction temperature
3. L = 41mH, V_{DD} = 50V, R_G = 25Ω, starting T_j = 25°C

Electrical Characteristics (SFET part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50μA	650	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=Max., Rating, VGS=0V	-	-	50	μA
		VDS=0.8Max., Rating, VGS=0V, TC=125°C	-	-	200	μA
Static Drain-Source on Resistance ^(Note)	RDS(ON)	VGS=10V, ID=1.5A	-	3.6	4.5	Ω
Forward Transconductance ^(Note)	gfs	VDS=50V, ID=1.5A	2.0	-	-	S
Input Capacitance	Ciss	VGS=0V, VDS=25V, f=1MHz	-	720	-	pF
Output Capacitance	Coss		-	40	-	
Reverse Transfer Capacitance	Crss		-	40	-	
Turn on Delay Time	td(on)	VDD=0.5BVDSS, ID=3.0A (MOSFET switching time are essentially independent of operating temperature)	-	150	-	nS
Rise Time	tr		-	100	-	
Turn Off Delay Time	td(off)		-	150	-	
Fall Time	tf		-	42	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	VGS=10V, ID=3.0A, VDS=0.5BVDSS (MOSFET switching time are essentially independent of operating temperature)	-	-	34	nC
Gate-Source Charge	Qgs		-	7.3	-	
Gate-Drain (Miller) Charge	Qgd		-	13.3	-	

Note:

1. Pulse test: Pulse width ≤ 300μS, duty cycle ≤ 2%

2. $S = \frac{1}{R}$

Electrical Characteristics (Control Part) (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
UVLO SECTION						
Start Threshold Voltage	VSTART	-	14	15	16	V
Stop Threshold Voltage	VSTOP	After turn on	9	10	11	V
OSCILLATOR SECTION						
Initial Accuracy	FOSC	KA1L0365R	45	50	55	kHz
		KA1M0365R	61	67	73	
		KA1H0365R	90	100	110	
Frequency Change With Temperature ⁽²⁾	$\Delta F/\Delta T$	-25°C ≤ Ta ≤ +85°C	-	±5	±10	%
Maximum Duty Cycle	Dmax	KA1L0365R	74	77	80	%
		KA1M0365R	74	77	80	
		KA1H0365R	64	67	70	
FEEDBACK SECTION						
Feedback Source Current	IFB	Ta=25°C, 0V ≤ Vfb ≤ 3V	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	VSD	-	6.9	7.5	8.1	V
Shutdown Delay Current	Idelay	Ta=25°C, 5V ≤ Vfb ≤ VSD	4.0	5.0	6.0	μA
REFERENCE SECTION						
Output Voltage ⁽¹⁾	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability ⁽¹⁾⁽²⁾	Vref/ΔT	-25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C
CURRENT LIMIT (SELF-PROTECTION) SECTION						
Peak Current Limit	I _{OVER}	Max. inductor current	1.89	2.15	2.41	A
PROTECTION SECTION						
Thermal Shutdown Temperature (Tj) ⁽¹⁾	TSD	-	140	160	-	°C
Over Voltage Protection Voltage	VOVP	-	23	25	28	V
TOTAL DEVICE SECTION						
Start-Up Current	I _{START}	V _{CC} =14V	0.1	0.3	0.4	mA
Operating Supply Current (Control Part Only)	I _{OP}	Ta=25°C	6	12	18	mA
V _{CC} Zener Voltage	V _Z	I _{CC} =20mA	30	32.5	35	V

Note:

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process

Typical Performance Characteristics

(These characteristic graphs are normalized at $T_a=25^\circ\text{C}$)

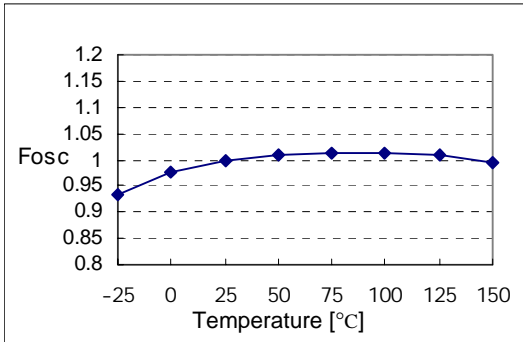


Figure 1. Operating Frequency

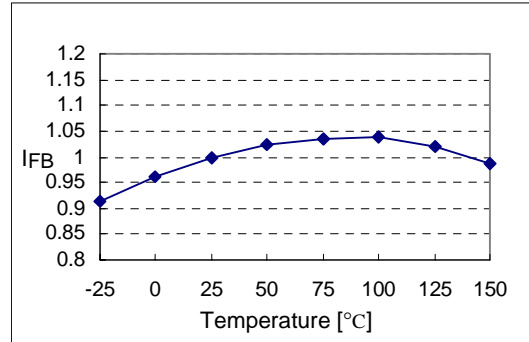


Figure 2. Feedback Source Current

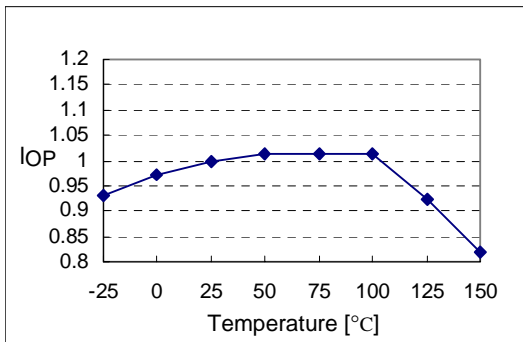


Figure 3. Operating Supply Current

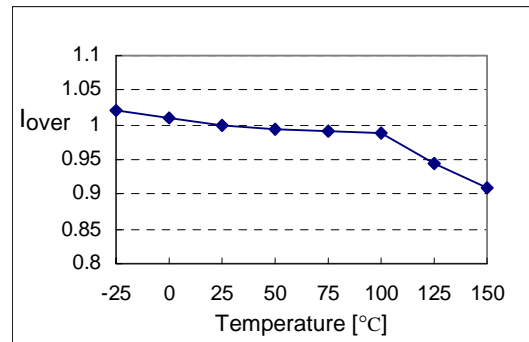


Figure 4. Peak Current Limit

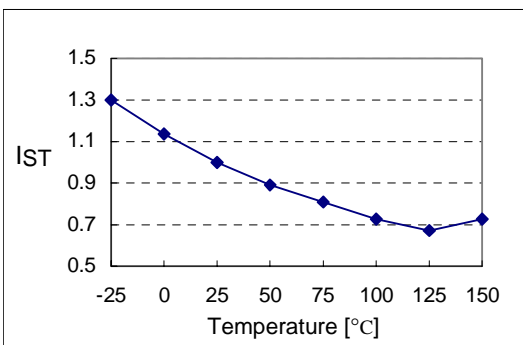


Figure 5. Start up Current

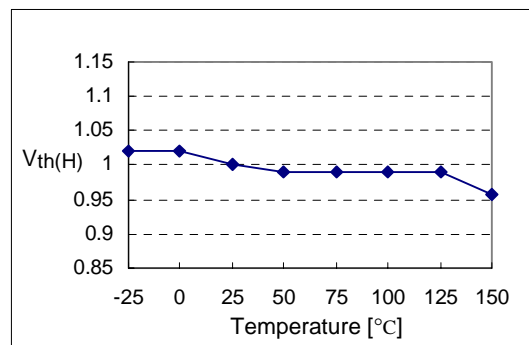


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

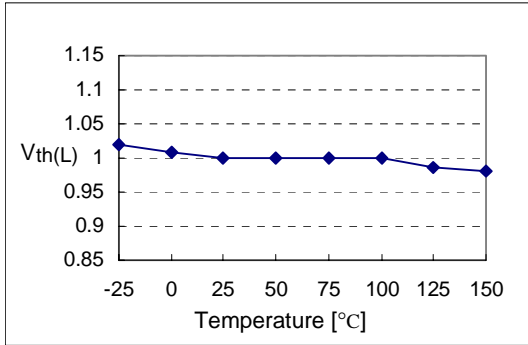


Figure 7. Stop Threshold Voltage

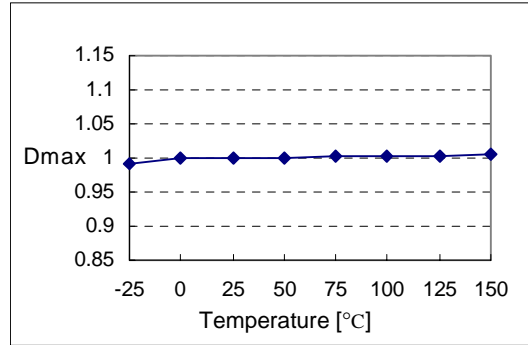


Figure 8. Maximum Duty Cycle

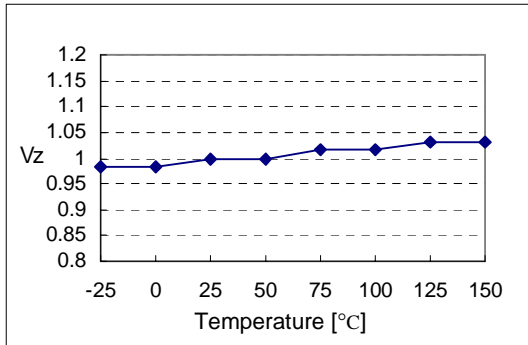


Figure 9. VCC Zener Voltage

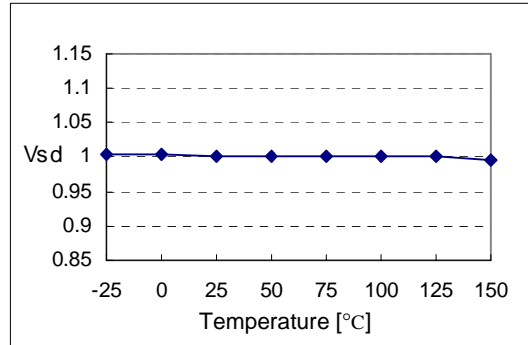


Figure 10. Shutdown Feedback Voltage

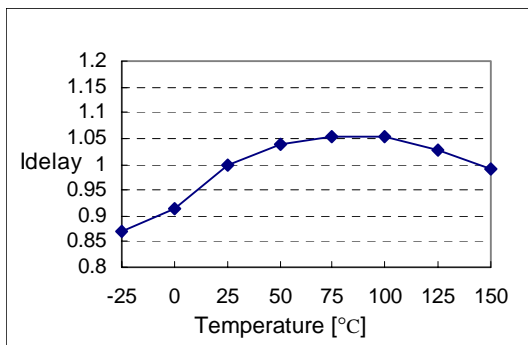


Figure 11. Shutdown Delay Current

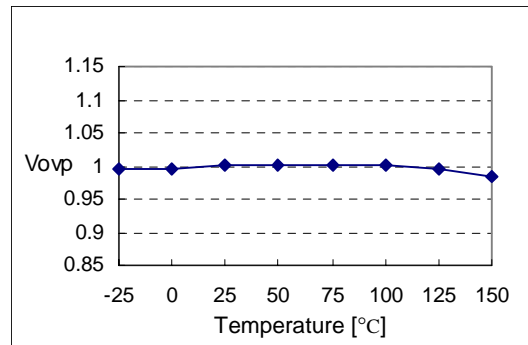


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic groups are normalized at $T_a=25^\circ\text{C}$)

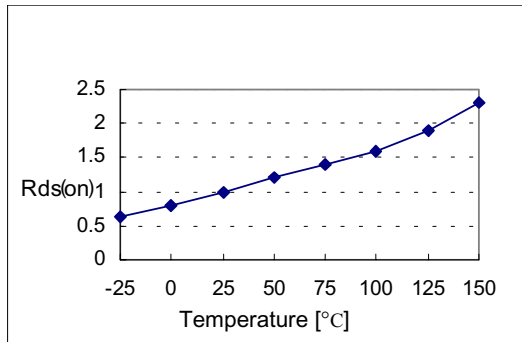
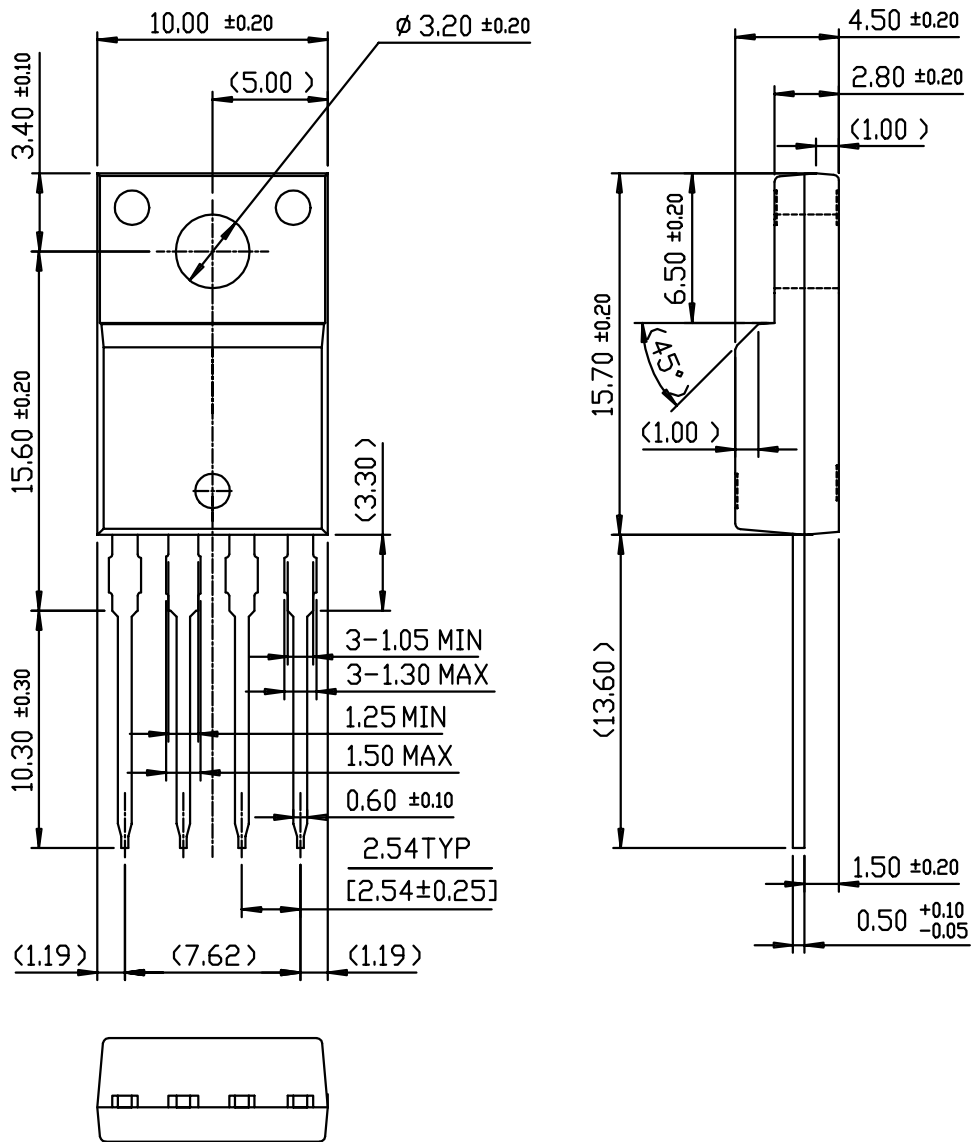


Figure 13. Static Drain-Source on Resistance

Package Dimensions

TO-220F-4L



Ordering Information

Product Number	Package	Rating	Fosc
KA1L0365R-TU	TO-220F-4L	650V, 3A	50kHz
KA1L0365R-YDTU	TO-220F-4L(Forming)		
KA1M0365R-TU	TO-220F-4L	650V, 3A	67kHz
KA1M0365R-YDTU	TO-220F-4L(Forming)		
KA1H0365R-TU	TO-220F-4L	650V, 3A	100kHz
KA1H0365R-YDTU	TO-220F-4L(Forming)		

TU : Non Forming Type

YDTU : Forming Type

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